

<b>Notice of References Cited</b>	Application/Control No. 10/699,668	Applicant(s)/Patent Under Reexamination KASAHARA, KENJI	
	Examiner Anh D. Mai	Art Unit 2814	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-6,100,954 A	08-2000	Kim et al.	349/138
	B	US-			
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	D	US-			
	E	US-			
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	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
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	V	S.H Won et al., Hdrogenated Amorphous Silicon Thin-Film Transistor on Plastic With an Organic Gate Insulator. IEEE 2004, pp. 132-134.
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.